NSN 5962-01-308-6356

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-308-6356 **Body Length:** Between 1.045 inches and 1.110 inches **Body Width:** Between 0.360 inches and 0.405 inches **Body Height:** Between 0.080 inches and 0.205 inches **Maximum Power Dissipation Rating:** 925.0 milliwatts **Operating Tempurature Range:** +0.0/+75.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and programmable and bipolar and w/enable and schottky **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level

output

Memory Device Type:

Terminal Type And Quantity:

22 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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